



# isc Silicon PNP Darlingtion Power Transistor

### **DESCRIPTION**

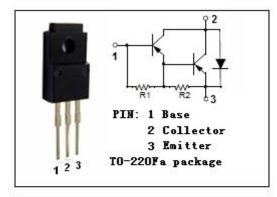
- · High DC C urrent Gain-
  - : h<sub>FE</sub>= 2000(Min.)@I<sub>C</sub>= -3A
- · Low Collector Saturation Voltage-
- : V<sub>CE(sat)</sub>= -1.5V(Max)@I<sub>C</sub>= -3A
- Good Linearity of h<sub>FE</sub>
- Complement to Type 2SD1416
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

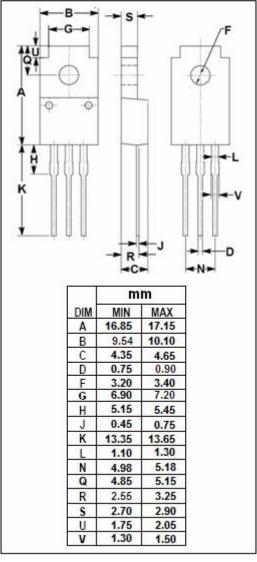


- · High power switching applications.
- Hammer drive, pulse motor drive applications.

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	-80	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	-80	V	
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V	
lc	Collector Current-Continuous	-7	А	
lв	Base Current-Continuous	-0.2	A	
P <sub>C</sub>	Collector Power Dissipation @ T <sub>a</sub> =25℃	2	W	
	Collector Power Dissipation @ T <sub>C</sub> =25℃	30		
TJ	Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	







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2SB1021

### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -30mA; I <sub>B</sub> = 0	-80			V
V <sub>CE(sat)-1</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -6mA			-1.5	V
V <sub>CE(sat)-2</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -7A; I <sub>B</sub> = -14mA			-2.0	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = -3A; I <sub>B</sub> = -6mA			-2.5	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = -80V; I <sub>E</sub> = 0			-100	μ <b>А</b>
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-4.0	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = -3A; V <sub>CE</sub> = -3V	2000		15000	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = -7A; V <sub>CE</sub> = -3V	1000			_

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